Direct observation of the class-B to class-A transition in the dynamical behavior of a semiconductor laser

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Abstract – The transition between the class-B and class-A dynamical behaviors of a semiconductor laser is directly observed by continuously controlling the lifetime of the photons in a cavity of sub-millimetric to centimetric length. It is experimentally and theoretically proved that the transition from a resonant to an overdamped behavior occurs progressively, without any discontinuity. In particular, the intermediate regime is found to exhibit features typical from both the class-A and class-B regimes. The laser intensity noise is proved to be a powerful probe of the laser dynamical behavior.

Since their discovery, lasers have been considered to be among the most exciting dynamical systems according to the wide variety of behaviors they offer. Laser dynamics is so rich that it became a tool of choice to analyze other dynamical systems even in new areas of physics. For instance, a fruitful analogy can be found between Bose-Einstein condensation and laser phase transition [1]. Although the laser is considered as a system far away from thermal equilibrium, tremendous theoretical and experimental studies have been carried out in order to find a thermodynamic reinterpretation of most laser phenomena. For instance, when the electromagnetic field is taken as the order parameter and the population inversion plays the role of temperature, laser threshold appears as a second-order phase transition [2,3]. Similar analogy is found in an active micro-cavity whose dimension is inferior to wavelength. It is shown that the transition occurring from spontaneous emission enhancement/inhibition, due to confinement, into collective stimulated emission can be reinterpreted as second-order phase transition by analogy with ferromagnetism and superconductivity [4]. First-order transition can also be observed in lasers. For instance, homogeneously broadened lasers can sustain the oscillation of two bistable optical fields. In this case, the laser field switching behaves as a first-order transition [5].

More generally, it has been well established for long that the dynamical behavior complexity of a system increases as the number of degrees of freedom increases, leading even to chaotic dynamics [6]. In the peculiar case of lasers, chaos can be obtained provided that more than two degrees of freedom are present in the system. Practical examples include lasers on which an external optical field, gain or loss feedback is applied in order to increase the number of degrees of freedom [7,8] or some molecular far infrared laser. In the case of single mode lasers, the number of degrees of freedom is determined by the time scale of the system constants, namely i) the active medium polarization decay rate $\gamma_\perp$, ii) the population decay rate $\gamma_\parallel$ and iii) the cavity decay rate $\gamma_{\text{cav}}$. Indeed, within the semiclassical approximation in which the atoms are treated quantum mechanically but the optical field is treated classically, the Maxwell-Bloch equations lead to five differential nonlinear equations whose resolution difficulty depends upon the time scale of $\tau_\perp = 1/\gamma_\perp$, $\tau_\parallel = 1/\gamma_\parallel$ and $\tau_{\text{cav}} = 1/\gamma_{\text{cav}}$. Following the early classification of Arecchi et al. [9], class-C lasers are those for which the three decay rates are of the same order of magnitude. This class includes some molecular far infrared lasers. Solving the Maxwell-Bloch equations gives rise to a large number of
solutions including chaotic behaviors. In class-B lasers the active medium polarization decays so rapidly that it can be adiabatically eliminated from the Maxwell-Bloch equations. The number of degrees of freedom is reduced to two, leading to a couple of so-called rate equations. Class-B includes most of the lasers used today such as solid-state lasers and semiconductor lasers. Finally, when the active medium polarization and population inversion both decay much faster than the optical field, the population inversion can be eliminated adiabatically as well. The system has one degree of freedom and the laser dynamics is then ruled by a single field equation. Most atomic gas lasers belong to this family.

The purpose of the present paper is to explore experimentally how the transition from class-B to class-A occurs. To this aim, we intend to probe the laser dynamics while the system evolves from two degrees of freedom to one degree of freedom. Although this transition can be modeled without too much difficulty, it has been not yet observed experimentally. Thus the agreement between the theoretical predictions and experimental results is still an open question.

Direct observation of class-B to class-A transition is not easy to handle experimentally because it relies on finding technical solutions to a certain number of constraints. As a starting point, the population inversion and cavity decay rates must be of the same order of magnitude. This situation can be reached using a semiconductor active medium in conjunction with a few millimeter-long high-finesse optical cavity. Second, one must be able to tune continuously one of the two decay rates while keeping the other parameters of the laser constant. The obvious approach is to adjust the photon cavity lifetime rather than the population inversion lifetime. Keeping in mind that the laser parameters must remain constant during class-A to class-B transition, the only way to change the cavity lifetime without modifying the other laser parameters, such as threshold and pumping rate, is to adjust the cavity length. Finally, the laser must remain single frequency within, and in between, the two boundary situations namely, class-A oscillation (long cavity) and class-B oscillation (short cavity). All these constraints can be fulfilled using a semiconductor active medium inserted into a dedicated tunable external cavity, as sketched in fig. 1. Following this approach, the active medium we have chosen is a half-Vertical Cavity Surface-Emitting Laser (half-VCSEL). A design based on a surface-emitting semiconductor is preferred to that of edge-emitting semiconductor because pure single mode operation is easier to obtain, in particular when the laser cavity becomes long. Furthermore, it is worthwhile to notice that common Vertical Cavity Surface-Emitting Lasers (VCSEL) belong to the class-B family. Their cavity length being in the micrometer range, the photon lifetime is shorter than the population inversion lifetime. Thus, their dynamics behave as a second-order filter exhibiting damped relaxation oscillations [10]. On the other hand, our recent experiments on intensity noise reduction in external cavity VCSELs have confirmed that when the optical cavity is long enough, so that the photon lifetime gets longer than the carrier lifetime, the laser dynamics behave as a low-pass first-order filter [11] proving that the laser operates in the class-A regime. Given that the two lasers in refs. [10] and [11,12] have active media of same nature whereas they exhibit two different dynamics, using a half-VCSEL in order to achieve a continuous transition from class-A to class-B regime is a good starting point.

In our experiment (see fig. 1), we have thus used the half-VCSEL whose structure is described in refs. [11,12]. When inserted inside an optical cavity and pumped at 808 nm, this structure oscillates at 1000 nm. To be able to reach sub-mm cavity lengths, the quantum wells in the active medium are pumped through the laser output coupler, which has a radius of curvature of 25 mm and a transmission equal to 1% at 1000 nm. In these conditions, the laser beam diameter for a 1 mm cavity length is of the order of 3 ns, we expect our VECSEL to lie between 1% (transmission of the output coupler) and 0.3 and 0.6 ns. Indeed, the cavity round-trip losses must be adiabatically eliminated from the Maxwell-Bloch equations. The number of degrees of freedom is reduced to two, leading to a couple of so-called rate equations. Class-B includes most of the lasers used today such as solid-state lasers and semiconductor lasers. Finally, when the active medium polarization and population inversion both decay much faster than the optical field, the population inversion can be eliminated adiabatically as well. The system has one degree of freedom and the laser dynamics is then ruled by a single field equation. Most atomic gas lasers belong to this family.

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We first choose a cavity short enough for the laser to exhibit a class-B dynamics. To this aim, we adjust the cavity length down to \( L = 0.85 \text{ mm} \). In these conditions, we expect the cavity photon lifetime \( \tau_{\text{cav}} \) to lie between 0.3 and 0.6 ns. Indeed, the cavity round-trip losses must be between 1% (transmission of the output coupler) and 2% (maximum gain of our half-VECESL). Since the carrier lifetime \( \tau_e \) is of the order of 3 ns, we expect our VCSEL to behave like a class-B laser with a relaxation oscillation.

![Fig. 1: (Colour on-line) Sketch of the experiment. The control of the cavity length \( L \) permits to control the photon decay rate \( \gamma_{\text{cav}} \). OIs are optical isolators, DM is a dichroic mirror, BS is a beam-splitter, and HWPs are half-wave plates.](image-url)
frequency \( f_r \) of the order of 100 MHz. To monitor the dynamical behavior of the laser, rather than measuring its modulation transfer function by modulating its gain or losses, we deduce this transfer function by observing how the pump laser intensity noise is transferred to the laser intensity noise [13]. It is indeed well known that the intensity noise of the laser is a good probe of the laser dynamics [14], provided the measured noise is well above the shot noise limit. We thus measure the VECSEL relative intensity noise (RIN) spectrum and divide it by the measured RIN spectrum of the pump laser (see fig. 1).

We call \( T_{\text{RIN}} \) the RIN transfer function, i.e., the ratio of these RIN values. Typical measurements of \( T_{\text{RIN}} \) vs. noise frequency are reproduced in fig. 2 for three values of the relative excitation \( r \) (pump power normalized to threshold) of the laser. These transfer functions exhibit the typical shape expected from a second-order resonant filter with a 40 dB/decade roll-off. Such a behavior is a signature of the class-B regime. The experimental spectra of fig. 2 are fitted using the following expression derived for class-B lasers [11]:

\[
T_{\text{RIN}}(f) = \frac{\gamma_f^2 \gamma_{\text{cav}} r^2}{[\gamma_f \gamma_{\text{cav}} (r-1) - (2\pi f)^2]^2 + (2\pi f \gamma_f r)^2}. \tag{1}
\]

Using eq. (1), the fits of fig. 2 lead to \( \tau_f = 3.3 \text{ ns} \) and \( \gamma_{\text{cav}} = 0.31 \text{ ns} \) for \( r = 1.39 \), \( \tau_f = 1.9 \text{ ns} \) and \( \gamma_{\text{cav}} = 0.31 \text{ ns} \) for \( r = 1.74 \), and \( \tau_f = 2.4 \text{ ns} \) and \( \gamma_{\text{cav}} = 0.40 \text{ ns} \) for \( r = 2.4 \). The corresponding values of the relaxation oscillation frequency \( f_\text{r} \) are 89, 133, and 179 MHz, respectively. The evolution of \( f_\text{r} \) vs. \( r \) is reproduced in the inset in fig. 2. It confirms that \( f_\text{r}^2 \) evolves linearly with \( (r-1) \), as expected for a class-B laser. Moreover, the value of the photon lifetime \( \tau_{\text{cav}} \) deduced from the fits is consistent with our initial guess and is ten times shorter than the carrier lifetime, proving also that the laser with \( L = 0.85 \text{ mm} \) is clearly a class-B laser. The variations in the values of \( \tau_f \) deduced from the fits can be attributed to measurement uncertainties and also to some dependence of this effective lifetime on the pump power.

In order to get closer to the class-B to class-A transition, we increase the photon lifetime from about 0.3 ns to about 0.8 ns by increasing the cavity length up to 1.26 mm. The corresponding transfer function is reproduced in fig. 3(a) for two values of \( r \). The fits using eq. (1) lead to \( \tau_f = 4.0 \text{ ns} \) and \( \gamma_{\text{cav}} = 0.71 \text{ ns} \) for \( r = 2.1 \), and \( \tau_f = 3.0 \text{ ns} \) and \( \gamma_{\text{cav}} = 0.82 \text{ ns} \) for \( r = 2.79 \). One can notice that the relaxation oscillations are barely visible on the two spectra of fig. 3(a), showing that we are closer to the class-A regime than in fig. 2. We go one step further by increasing the cavity length up to \( L = 2.0 \text{ mm} \). The corresponding measured transfer function is reproduced in fig. 3(b). We can see that the resonance has disappeared (compare with figs. 3(a) and 2). The transfer function now looks like a low-pass filter, a feature usually considered to be typical of class-A laser. However, the roll-off is still equal to 40 dB/decade, which is typical of class-B lasers [15]. We are thus exactly in the intermediate case in which the laser behavior exhibits features from both the class-A and class-B regimes. This is consistent with the fact that the fit using eq. (1) gives values of \( \tau_f \) and \( \gamma_{\text{cav}} \) which are of the same order of magnitude (\( \tau_f = 2.8 \text{ ns} \) and \( \gamma_{\text{cav}} = 1.4 \text{ ns} \)). It is worth noting that the vanishing of the relaxation oscillations in the spectrum of fig. 3(b) is a direct signature of a modification of the laser dynamics at the border between the class-A and class-B regimes. It is different from the overdamping of relaxation oscillations that occurs in diode lasers due to spontaneous emission or to gain compression [16].

When the laser becomes really a class-A laser, then \( \gamma_{\text{cav}} \ll \gamma_f \), and, for \( f \ll \gamma_f / 2\pi \), eq. (1) becomes

\[
T_{\text{RIN}}(f) = \frac{\gamma_f^2 \gamma_{\text{cav}}}{[\gamma_f (r-1) - (2\pi f)^2]^2 + (2\pi f \gamma_f)^2}. \tag{2}
\]

This is the transfer function of a first-order low-pass filter, with a cut-off frequency given by \( (r-1) \gamma_{\text{cav}} / 2\pi \) and a 20 dB/decade roll-off. To reach this regime, we increase the cavity length up to \( L = 44 \text{ mm} \). The output coupler now has a 50 mm radius of curvature and has again a 1% transmission at 1000 nm. In this cavity, the structure is no longer pumped through the output coupler but from the side of the cavity (for details, see [11, 12]). A 150 \( \mu \text{m} \) etalon forces the laser to operate in single-frequency regime. Now the laser transfer function exhibits a 20 dB/decade roll-off, and can be fitted using eq. (2), as shown by the full line in fig. 4. It leads to \( \tau_{\text{cav}} = 9.8 \text{ ns} \) (corresponding to 1.5% losses per round-trip) which is indeed much longer than \( \tau_f \). This proves definitely that the laser has now reached a pure class-A behavior. The transition from the class-B to class-A regime is also clearly seen the inset of fig. 4, which displays the evolution of the noise transfer function at a fixed frequency (50 MHz) with the photon lifetime. In this inset, the theoretical plot has been obtained using eq. (1) with \( r = 1.89 \) and \( \tau_f = 2.9 \text{ ns} \) and the experimental dots...
correspond to \( r \) close to 2. The abrupt decrease of \( T_{\text{RIN}} \) vs. \( \tau_{\text{cav}} \) is a clear signature of the transition.

In conclusion, the transition from class-B to class-A dynamics has been directly observed by continuously modifying the photon lifetime in a dedicated single mode laser cavity. Such a continuous modification of the photon lifetime is also an original contribution of the present work. We have proved that the class-B to class-A transition occurs progressively, as expected theoretically. Furthermore, we have been able to isolate an intermediate regime in which the laser exhibits simultaneously features typical of the two regimes. Indeed, the relaxation oscillations disappear as expected from class-A lasers, while the transfer function roll-off is still characteristic of class-B lasers. This proves that the different laser classes are not completely leakproof categories, contrary to what could be believed from a large part of the literature on laser dynamics. These observations have been made technically possible by obtaining single mode oscillation in a very low losses sub-mm optical resonator including an active medium whose population inversion decay time is of the same order of magnitude of the resonator decay time and whose polarization can be eliminated adiabatically. The laser intensity noise in such a system is shown to be a powerful probe of the laser dynamics.

The control of the exact conditions in which a laser switches from class-A to class-B dynamics is important for the control of the intensity noise in MEMS-VCSELs. Indeed, one wants the cavity to be as short as possible to extend the laser tuning range while keeping the laser quiet in order to maximize the signal-to-noise ratio when the laser is used to probe absorption [17]. Controlling the nature of the laser dynamics is also important in fundamental studies aiming at understanding the role played by the enhancement of the spontaneous emission in the laser relaxation oscillations and noise [18].

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